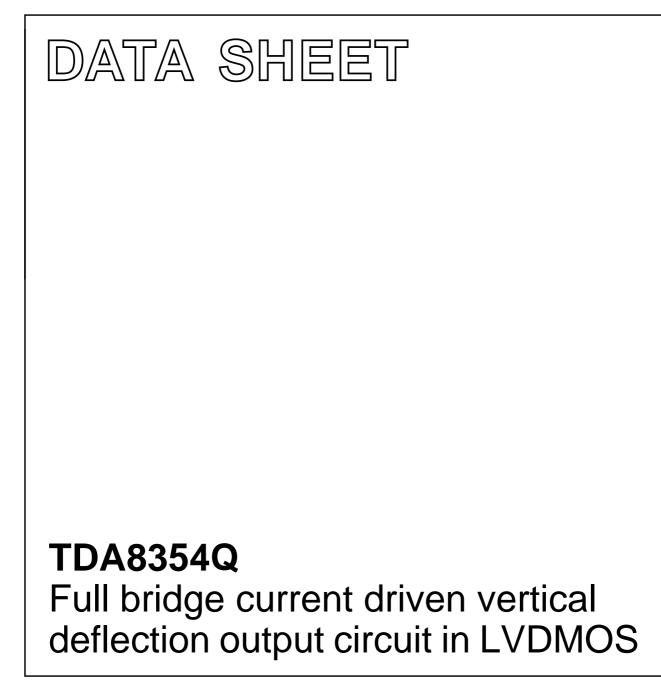
INTEGRATED CIRCUITS



Preliminary specification File under Integrated Circuits, IC02 1998 Sep 03



TDA8354Q

FEATURES

- · Few external components
- · Highly efficient fully DC-coupled vertical output bridge circuit
- Short rise and fall times of the vertical flyback switch
- · Guard circuit

- Temperature (thermal) protection
- · High ElectroMagnetic Compatibility (EMC) because of common mode inputs
- Guard signal in zoom mode.

QUICK REFERENCE DATA

GENERAL DESCRIPTION

The TDA8354Q is a power circuit for use in 90° and 110° colour deflection systems for field frequencies of 25 to 200 Hz and 16 : 9 picture tubes. The circuit provides a DC-driven vertical deflection output circuit, operating as a highly efficient class G system. Due to the full bridge output circuit the deflection coils can be DC coupled.

The IC is constructed in a low-voltage DMOS process that combines bipolar, CMOS and DMOS devices, to provide ruggedness.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
DC supply						
V _P	supply voltage		7.5	12	18	V
I _{q(av)}	average quiescent supply current	during scan	_	10	15	mA
V _{flb}	flyback supply voltage		$2 \times V_P$	45	68	V
I _{Vflb(av)}	average flyback supply current	during scan	_	-	10	mA
Vertical circu	iit					
I _{o(p-p)}	output current (peak-to-peak value)		-	-	3.2	А
I _{i(diff)(p-p)}	input current (peak-to-peak value) at pin 11 or 12		-	500	600	μA
Flyback swit	ch					
I _{o(Vflb)}	peak output current	t ≤ 1.5 ms	-	-	±1.6	А
Thermal data	(in accordance with IEC 747-1)					
T _{stg}	storage temperature		-55	-	+150	°C
T _{amb}	operating ambient temperature		-25	-	+75	°C
Тį	junction temperature		_	_	150	°C

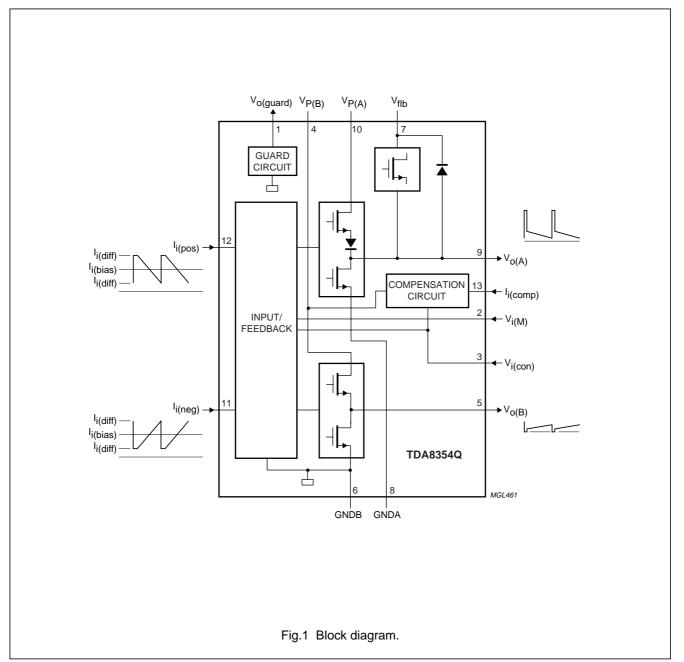
ORDERING INFORMATION

ТҮРЕ		PACKAGE	
NUMBER	NAME	DESCRIPTION	VERSION
TDA8354Q	DBS13P	plastic DIL-bent-SIL power package; 13 leads (lead length 12 mm)	SOT141-6

TDA8354Q

Full bridge current driven vertical deflection output circuit in LVDMOS

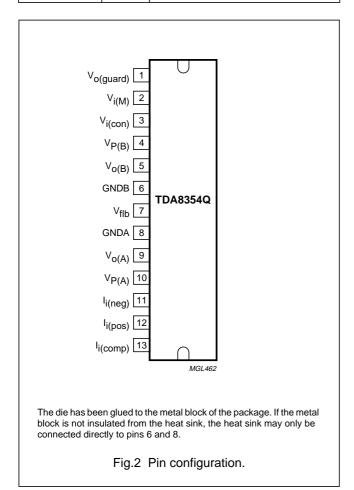
BLOCK DIAGRAM



TDA8354Q

PINNING

SYMBOL	PIN	DESCRIPTION
V _{o(guard)}	1	guard output voltage
V _{i(M)}	2	measuring resistor input
V _{i(con)}	3	conversion resistor input
V _{P(B)}	4	supply voltage B
V _{o(B)}	5	output voltage B
GNDB	6	ground B
V _{flb}	7	flyback supply voltage
GNDA	8	ground A
V _{o(A)}	9	output voltage A
V _{P(A)}	10	supply voltage A
I _{i(neg)}	11	input power-stage (negative); includes l _{i(bias)} signal bias
l _{i(pos)}	12	input power-stage (positive); includes l _{i(bias)} signal bias
I _{i(comp)}	13	damping resistor compensation current input



FUNCTIONAL DESCRIPTION

The vertical driver circuit is a bridge configuration. The deflection coil is connected between the output amplifiers, which are driven in phase opposition. The differential input circuit is current driven. The input circuit is special intended for direct connection to driver circuits which deliver symmetrical current signals, but is also suitable for asymmetrical currents. The current to voltage conversion is done by the external resistor (R_{con}) connected between the output of the input conversion stage and output stage B. This voltage is compared with the output current through the deflection coil measured as voltage across R_M, which provides internal feedback information. The relationship between the differential input current and the output current is defined by: $2 \times I_{i(diff)} \times R_{con} = I_{coil} \times R_M$ The output current is adjustable from 0.5 A (p-p) to 3.2 A (p-p) by varying R_{con}. The maximum input current is 800 µA peak for each pin. The minimum input current should be 50 μ A.

Flyback supply

The flyback voltage is determined by an additional supply voltage V_{flb}. The principle of operating with two supply voltages (class G) makes it possible to fix the supply voltage V_P optimum for the scan voltage and the second supply voltage V_{flb} optimum for the flyback voltage. Using this method, very high efficiency is achieved. The supply voltage V_{flb} is almost totally available as flyback voltage across the coil, this being possible due to the absence of a coupling capacitor (not necessary, due to the bridge configuration). The very short rise and fall time of the flyback switch is >400 V/µs.

Protection

The output circuit has protection circuits for:

- Die temperature control
- Overvoltage of output stage A.

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Guard circuit

A guard circuit with output signal $V_{o(guard)}$ is provided.

The guard circuit generates an active HIGH level during the flyback period. The guard circuit is also activated for one or more of the following conditions:

- When the thermal protection is activated ($T_i \approx 170 \text{ °C}$)
- During short-circuit of the output pins (pins 5 and 9) to V_{P} or ground
- During open coil
- During open loop
- During short-circuit of the input pins (pins 11 and 12) to $V_{\rm P}$ or ground.

An active HIGH level of the guard signal is also generated for the next conditions:

- No drive signal
- Short-circuit of the coil.

However, for these events the signal is generated via an internal timer circuit. The guard signal set via this timer has a delay of \approx 120 ms. The delay time is given by the lowest applicable field frequency.

The guard signal can be used for blanking the picture tube screen and signalling a fault condition.

Damping resistor compensation

For HF-loop stability a damping resistor is connected across the deflection coil. There is a big difference in current in the damping resistor R_p during scan and flyback. The resistor current is summed to the current in the deflection coil via the measuring resistor R_M , which results in a too low current in the deflection coil at the start of the scan.

To reach a short settling time the difference in the current during scan and flyback in the damping resistor can be compensated for by external means. To do so a resistor (R_{comp}) of about 1 M Ω can be connected between the output of stage A (pin 9) and the damping resistor compensation current input (pin 13).

For a more accurate calculation of $\mathsf{R}_{\mathsf{comp}}$ refer to the following formula:

$$R_{comp} = \frac{(V_{flb} - V_{loss} - V_{p}) \times R_{p} \times R_{con}}{(V_{flb} - V_{loss} - I_{L} \times R_{L}) \times R_{M}}$$

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
DC supply		·	ŀ		•
VP	supply voltage		_	18	V
V _{flb}	flyback supply voltage		-	68	V
Vertical circu	Jit	•			•
I _{o(p-p)}	output current (peak-to-peak value)		_	3.2	А
V _{o(A)}	output voltage (pin 9)	note 1	-	68	V
V _{o(B)}	output voltage (pin 5)		-	V _P	V
I _{1,2,3,11,12,13}	current into or out of pins 1 to 3 and 11 to 13		-20	+20	mA
V _{1,2,3,11,12,13}	peak voltage on pins 1 to 3 and 11 to 13		-0.5	V _P	V
Flyback swit	ch	·			•
I _{o(Vflb)}	peak output current		-	±1.6	А
Thermal data	a (in accordance with IEC 747-1)				
T _{stg}	storage temperature		-55	+150	°C
T _{amb}	operating ambient temperature		-25	+75	°C
Tj	junction temperature	note 2	-	150	°C
Miscellaneou	us				
t _{sc}	short-circuiting time	note 3	_	1	h
l _{i/o}	current into any pin	+1.5 × $ V_{P(max)} $; note 4	-	+200	mA
	current out of any pin	$-1.5 \times V_{P(max)} $; note 4	-200	_	mA
V _{ESD}	electrostatic handling	note 5	-	±300	V
		note 6	-	±2000	V

Notes

1. When the pin voltage exceeds 70 V the device behaves like a power zener diode thus limiting the voltage.

- 2. Internally limited by thermal protection; switching point \approx 170 °C.
- 3. Up to $V_P = 18 V$.
- 4. At T_{j(max)}.

5. Machine model: equivalent to discharge a 200 pF capacitor through a 0 Ω series resistor. Except pin 7: ±250 V.

6. Human body model: equivalent to discharge a 100 pF capacitor through a 1.5 k Ω series resistor. Except pin 7: ± 1500 V.

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-c)}	thermal resistance from junction to case		4	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	40	K/W

CHARACTERISTICS

 V_P = 12 V; V_{flb} = 45 V; f_i = 50 Hz; $I_{i(bias)}$ = 330 μ A; T_{amb} = 25 °C; measured in test circuit of Fig.3; unless otherwise specified.

SYMBOL	PARAMETER	PARAMETER CONDITIONS				
DC supply		•				
VP	operating supply voltage		7.5	12	18	V
V _{flb}	flyback supply voltage		$2 \times V_P$	45	68	V
I _{q(av)}	average quiescent supply current	during scan	_	10	15	mA
lq	quiescent supply current	no signal; no load	_	60	80	mA
I _{Vflb(av)}	average flyback supply current	during scan	_	-	10	mA
Output stag	e A and B	•				
V _{loss}	voltage loss from pin 10 to 9 and from pin 5 to 6	I _o = 3.2 A (p-p); note 1	-	-	6.0	V
	voltage loss from pin 4 to 5 and from pin 9 to 8		-	-	4.8	V
	voltage loss from pin 10 to 9 and from pin 5 to 6	I _o = 2.2 A (p-p); note 1	-	-	4.2	V
	voltage loss from pin 4 to 5 and from pin 9 to 8		-	-	3.4	V
LE	linearity error					
	adjacent blocks	I _o = 3.2 A (p-p); note 2	-	0.5	2	%
	not adjacent blocks	I _o = 3.2 A (p-p); note 2	-	0.5	3	%
Vo	output voltage swing (flyback) $V_{o(A)} - V_{o(B)}$	$I_{i(diff)} = 0.3 \text{ mA};$ $I_{o} = 1.6 \text{ A}$	-	46	-	V
V _{offset}	offset voltage across R _M	$I_{i(diff)} = 0$				
		$I_{i(bias)} = 500 \ \mu A$	-	_	15	mV
		l _{i(bias)} = 100 μA	-	-	13	mV
$\Delta V_{\text{offset}(T)}$	offset voltage as function of temperature	$I_{i(diff)} = 0$	-	-	40	μV/K
V _{o(A)} , V _{o(B)}	DC output voltage	$I_{i(diff)} = 0;$ note 3	-	$\frac{V_P}{2}$	-	V
G _{v(ol)}	open-loop voltage gain V _{9 to 5} /V _{3 to 5}	notes 4 and 5	_	60	-	dB
V _{3 to 5} /V _{2 to 5}		note 4	-	0	-	dB
f _{res}	frequency response (-3 dB)	open loop	_	1	-	kHz
G _i	current gain (I _o /I _{i(diff)})		_	8000	_	

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
$\Delta G_{i(T)}$	current gain drift as function of temperature		-	-	10-4	/K	
PSRR	power supply rejection ratio	note 6	80	90	-	dB	
Input stage							
I _{i(bias)}	signal bias current		-	330	500	μA	
I _{i(diff)(p-p)}	differential mode input current (peak-to-peak value) pin 11 or 12	note 7	-	500	600	μA	
V _{i(diff)}	differential mode input voltage	l _{i(diff)} = 500 μA	-	0.75	_	V	
V _{i(cm)}	common mode input voltage	I _{i(bias)} = 330 μA	0.95	1.15	1.35	V	
Flyback sw	itch	•				•	
I _{o(Vflb)}	output peak current	t < 1.5 ms	-	-	±1.6	А	
V _{loss}	voltage loss (V _{flb} – V _{o(A)})	I _o = +1.6 A	-	8	9	V	
Guard circu	lit						
I _{o(guard)}	output current	not active; V _{o(guard)} = 0 V	-	_	10	μA	
		active; V _{o(guard)} = 4.5 V	1	-	2.5	mA	
V _{o(guard)}	output voltage on pin 1	I _{o(guard)} = 100 μA	5	6	7	V	
	allowable voltage on pin 1	maximum leakage current = 10 μ A	_	-	18	V	

Notes

1. At $T_i = 125$ °C. The temperature coefficient of V_{loss} has a positive sign.

2. The linearity error is measured without S correction and based on the same measurement principle as performed on the screen. The measuring method is as follows:

Divide the output signal into 22 equal time parts ranging from 1 to 22 inclusive. Measure the value of the voltage across R_M of two succeeding parts called one block (a) starting with part 2 and 3 (block 1) and ending with part 20 and 21 (block 10). Thus parts 1 and 22 are unused. The equations for linearity error for adjacent blocks (LEAB) and not adjacent blocks (LENAB) are given below:

$$LEAB = \frac{a_k - a_{(k+1)}}{a_{av}}$$
$$LENAB = \frac{a_{max} - a_{min}}{a_{av}}$$

3. $V_{o(A)} + V_{o(B)} = V_P$. At the start of the scan this equation is one diode voltage less.

- 4. The V value within formulae relates to voltages at or between relative pin numbers, i.e. $V_{9 \text{ to } 5}/V_{3 \text{ to } 5}$ = voltage value across pins 9 and 5 divided by voltage value across pins 3 and 5.
- 5. $V_{2 to 5}$ AC short-circuited.
- 6. At $V_{(ripple)} = 500 \text{ mV}$ (eff) at V_P ; measured across R_M ; $f_{(ripple)} = 50 \text{ Hz} 1 \text{ kHz}$.
- 7. $I_{i(bias)} + I_{i(diff)} \le 800 \ \mu A \ and \ I_{i(bias)} I_{i(diff)} \ge 50 \ \mu A \ per \ pin.$

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INTERNAL CIRCUITRY

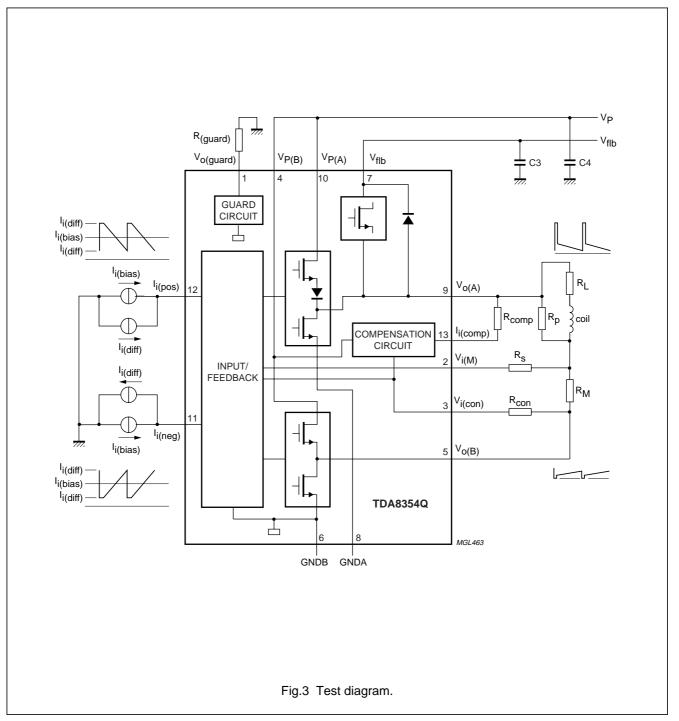
 Table 1
 Equivalent pin circuits

PIN	SYMBOL	EQUIVALENT CIRCUIT
1	V _{o(guard)}	
2	V _{i(M)}	
3	V _{i(con)}	
4	V _{P(B)}	(4)
5	V _{o(B)}	
6	GNDB	(5) (6) (6) (6) (6) (6) (6) (6) (6) (6) (6

EQUIVALENT CIRCUIT PIN SYMBOL 7 $\mathsf{V}_{\mathsf{flb}}$ (10) GNDA 8 9 V_{o(A)} 10 V_{P(A)} (9) (8) (7)MGL471 11 I_{i(neg)} <u>300 Ω</u> (11) Т MGL470 12 I_{i(pos)} <u>300 Ω</u> (12) Ь MGL469 13 I_{i(comp)} <u>300 Ω</u> (13) Г MGL468

TDA8354Q

TEST AND APPLICATION INFORMATION



TDA8354Q

Full bridge current driven vertical deflection output circuit in LVDMOS

٧P 77 R_(guard) V_{flb} + + C3 V_{P(A)} C1 C4 C2 Vo(guard) VP(B) V_{flb} 4 10 7 C5 GUARD CIRCUIT ٦Ь ╘ li(diff) li(bias) li(diff) li(pos) V_{o(A)} 12 9 R_{comp} Rp coil COMPENSATION li(comp) 13 CIRCUIT Rs DEFLECTION V_{i(M)} 2 PROCESSOR INPUT/ FEEDBACK RM R_{con} Vi(con) 3 li(neg) 11 V_{o(B)} 5 li(diff) li(bias) li(diff) TDA8354Q L MGL464 GNDB GNDA $R_M = 0.5 \Omega;$ Coil: AT6216/42; $C1 = 47 \ \mu F; 100 \ V;$ $V_P = 12.1 \text{ V}$ at $f_v = 50 \text{ Hz}$ (vertical frame frequency); inclusive spread (absolute) and $R_{con} = R_s = 1.2 \text{ k}\Omega;$ C2 = 220 µF; 25 V; temperature rise in the coil; R_p = 300 Ω; C3 = C4 = 100 nF; $R_{comp} = 650 \text{ k}\Omega;$ C5 = 10 nF;C6 = C7 = 10 nF. $V_{P} = 12.8 \text{ V}$ at $f_{v} = 100 \text{ Hz}$ (vertical frame frequency); inclusive spread (absolute) and temperature rise in the coil; $R_{(guard)} = 5 k\Omega.$ $$\begin{split} I_{o(p-p)} &= 2.33 \text{ A (peak-to-peak);} \\ I_{i(bias)} &= 330 \, \mu\text{A;} \\ \end{split}$$ $I_{i(diff)(12\text{-}11)} = 485 \ \mu\text{A}$ (peak value); $V_{flb} = 45 \ \text{V};$ $t_{flb} = 0.6 \text{ ms}.$ Fig.4 Application diagram.

1998 Sep 03

PACKAGE OUTLINE

S13P:	plas	stic C	DIL-be	ent-S	IL po	wer	pack	age;	13 le	ads ((lead	leng	th 12	mm)						SC	DT14
					D							non-co □ ↓ E _h —									
-				_ `	d				↓ j									v (M)			
IMENSI	IONS (mm ai	re the c	origina	l dime	nsions	.)		0	5 l sca		10 m 	m								
UNIT	A	A ₂	b _p	c	D ⁽¹⁾	d	D _h	E ⁽¹⁾	е	e ₁	e ₂	E _h	j	L	L ₃	m	Q	v	w	x	Z ⁽¹⁾
mm	17.0 15.5	4.6 4.2	0.75 0.60	0.48 0.38	24.0 23.6	20.0 19.6	10	12.2 11.8	3.4	1.7	5.08	6	3.4 3.1	12.4 11.0	2.4 1.6	4.3	2.1 1.8	0.8	0.25	0.03	2.00 1.45
			trusion	s of 0.2	5 mm	maxim	um pei	r side ar REFE			ed.]		EUR	OPEA	N			
ou	OUTLINE VERSION IEC							EIAJ							PROJECTION IS				SUE DATE		
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SOLDERING

Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (order code 9398 652 90011).

Soldering by dipping or by wave

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ($T_{stg\,max}$). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

Repairing soldered joints

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

DEFINITIONS

Data sheet status						
Objective specification This data sheet contains target or goal specifications for product development.						
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.					
Product specification	This data sheet contains final product specifications.					
Limiting values						
more of the limiting values r of the device at these or at	accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or nay cause permanent damage to the device. These are stress ratings only and operation any other conditions above those given in the Characteristics sections of the specification imiting values for extended periods may affect device reliability.					
Application information						
Where application information is given, it is advisory and does not form part of the specification.						

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Preliminary specification

Full bridge current driven vertical deflection output circuit in LVDMOS

TDA8354Q

NOTES

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